S28	0	anodic adj foil and hydrat$3 same barrier same layer and(361/523-528).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:27
S29	0	anodic adj foil and hydrat$3 and barrier same layer and(361/523-528).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:28
S30	8	electrolytic same capacitor and hydrat$3 and barrier same layer and(361/523-528).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:29
S31	6	S30 and(anodiz$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:28
S32	6	S31 and(acid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:56
S33	4	electrolytic same capacitor and hydrat$3 and barrier same layer and(29/25.03).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:29
S34	0	anodiz$3 same nano adj porous adj amorphous adj oxide adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:57
S35	0	anodiz$3 same porous adj amorphous adj oxide adj layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:57

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	10	US-4518471-$.DID. OR US-4525249-$.DID. OR US-5151388-$.DID. OR US-5449448-$.DID. OR US-5715133-$.DID.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:20
S2	2	S1 and(hydrat$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:21
S3	0	S2 and(anodiz$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:21
S4	0	S1 and(anodiz$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:21
S5	0	S2 and(barrier same layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:22
S6	0	S1 and(barrier same layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:22
S7	8	anod$2 adj foil same anodizing adj foil	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:22
S8	5	S7 and hydrat$3 same foil	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 12:41

S9	1	S8 and(barrier same layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/29 10:23
S10	2	"5424906".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 08:42
S11	1	"6459565".PN.	USPAT; USOCR	OR	OFF	2005/07/01 08:38
S12	1	"6409905".PN.	USPAT; USOCR	OR	OFF	2005/07/01 08:39
S13	1	"5935408".PN.	USPAT; USOCR	OR	OFF	2005/07/01 08:40
S14	1	"5674371".PN.	USPAT; USOCR	OR	OFF	2005/07/01 08:41
S15	1	"5158663".PN.	USPAT; USOCR	OR	OFF	2005/07/01 08:41
S16	5	"6450565"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 08:43
S17	984	anodiz$3 same capacitor and acid	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 08:44
S18	273	anodiz$3 same capacitor and sulfuric adj acid	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 08:44
S19	101	S18 and(oxide adj layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 08:44

S20	8	S19 and(hydrat$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:26
S21	76	"4910645"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:29
S22	13	S21 and(hydrat$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:23
S23	13	S22 and(anodiz$3 same foil)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:23
S24	8	S23 and(barrier same layer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:24
S25	8	S24 and(acid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:24
S26	0	"4910645.pn."	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:29
S27	2	"4910645".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 09:29

S36	0	anodiz$3 same porous adj amorphous adj oxide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:57
S37	0	anodiz$3 same porous adj amorphous3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:58
S38	0	anodiz$3 and porous adj amorphous3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/01 10:58
S39	7	anodiz$3 same porous adj amorphous	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 09:36
S40	49891	hydrat$3 same water same temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:03
S41	131	S40 same anodiz$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:03
S42	22	S41 and(electrolytic adj capacitor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:03
S43	301	hydrat$3 adj step same water same temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:03

S44	2	S43 same anodiz$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:03
S45	1	S43 and(electrolytic adj capacitor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:14
S46	0	S45 and(anodiz$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 10:15
S47	1	S45 and(etch$3 or forming)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/05 16:27
S48	64	dielectric adj layer same single adj phase	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:36
S49	0	ELECTRODECERAMIC ADJ COMPONENT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:37
S50	25	ELECTROCERAMIC ADJ COMPONENT	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:37
S51	6	S50 AND(DIELECTRIC)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:40

S52	1409	SILVER SAME NIOBIUM SAME TANTALUM SAME OXIDE	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:40
S53	456	S52 AND DIELECTRIC	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:42
S54	110	S53 AND(DIELECTRIC ADJ CONSTANT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:42
S55	64	S54 AND(ROOM ADJ TEMPERATURE)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/06 10:43